

To our customers,

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## Old Company Name in Catalogs and Other Documents

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On April 1<sup>st</sup>, 2010, NEC Electronics Corporation merged with Renesas Technology Corporation, and Renesas Electronics Corporation took over all the business of both companies. Therefore, although the old company name remains in this document, it is a valid Renesas Electronics document. We appreciate your understanding.

Renesas Electronics website: <http://www.renesas.com>

April 1<sup>st</sup>, 2010  
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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Not recommended  
for new design

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SWITCHING  
N- AND P-CHANNEL POWER MOS FET

DESCRIPTION

The  $\mu$ PA1792 is N- and P-channel MOS Field Effect Transistors designed for Motor Drive application of HDD and so on.

FEATURES

- Low on-state resistance

N-channel  $R_{DS(on)1} = 26 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = 10 \text{ V}$ ,  $I_D = 3.4 \text{ A}$ )

$R_{DS(on)2} = 36 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = 4.5 \text{ V}$ ,  $I_D = 3.4 \text{ A}$ )

$R_{DS(on)3} = 42 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = 4.0 \text{ V}$ ,  $I_D = 3.4 \text{ A}$ )

P-channel  $R_{DS(on)1} = 36 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = -10 \text{ V}$ ,  $I_D = -2.9 \text{ A}$ )

$R_{DS(on)2} = 54 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = -4.5 \text{ V}$ ,  $I_D = -2.9 \text{ A}$ )

$R_{DS(on)3} = 65 \text{ m}\Omega \text{ MAX.}$  ( $V_{GS} = -4.0 \text{ V}$ ,  $I_D = -2.9 \text{ A}$ )

- Low input capacitance

N-channel  $C_{iss} = 760 \text{ pF TYP.}$

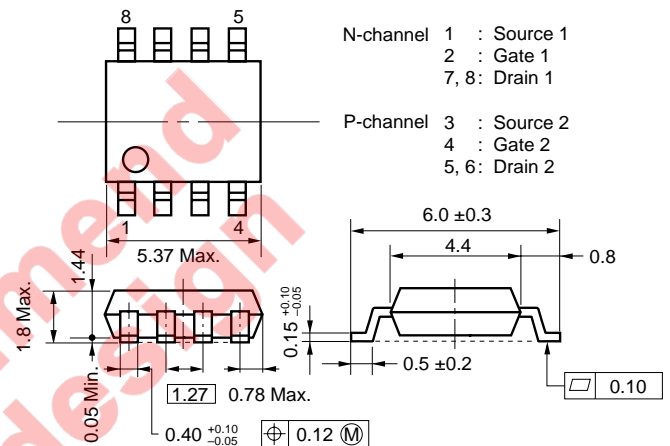
P-channel  $C_{iss} = 900 \text{ pF TYP.}$

- Built-in G-S protection diode
- Small and surface mount package (Power SOP8)

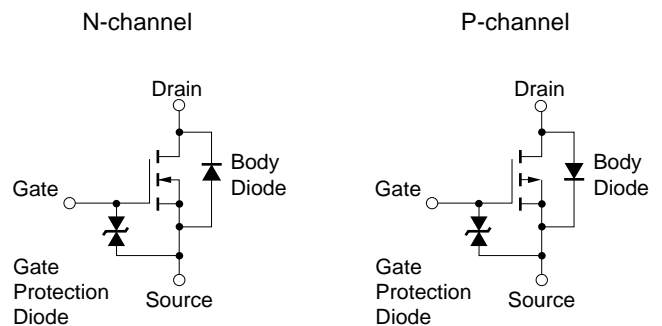
ORDERING INFORMATION

PART NUMBER	PACKAGE
$\mu$ PA1792G	Power SOP8

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUIT



**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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**ABSOLUTE MAXIMUM RATINGS (T<sub>A</sub> = 25°C. All terminals are connected.)**

PARAMETER	SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Drain to Source Voltage (V <sub>GS</sub> = 0 V)	V <sub>DSS</sub>	30	-30	V
Gate to Source Voltage (V <sub>DS</sub> = 0 V)	V <sub>GSS</sub>	±20	∓20	V
Drain Current (DC)	I <sub>D(DC)</sub>	±6.8	∓5.8	A
Drain Current (pulse) <sup>Note1</sup>	I <sub>D(pulse)</sub>	±27.2	∓23.2	A
Total Power Dissipation (1 unit) <sup>Note2</sup>	P <sub>T</sub>	1.7		W
Total Power Dissipation (2 units) <sup>Note2</sup>	P <sub>T</sub>	2.0		W
Channel Temperature	T <sub>ch</sub>	150		°C
Storage Temperature	T <sub>stg</sub>	-55 to +150		°C

**Notes 1.** PW ≤ 10 μs, Duty Cycle ≤ 1%

**2.** Mounted on ceramic substrate of 2000 mm<sup>2</sup> x 1.6 mm

Not recommend  
for new design

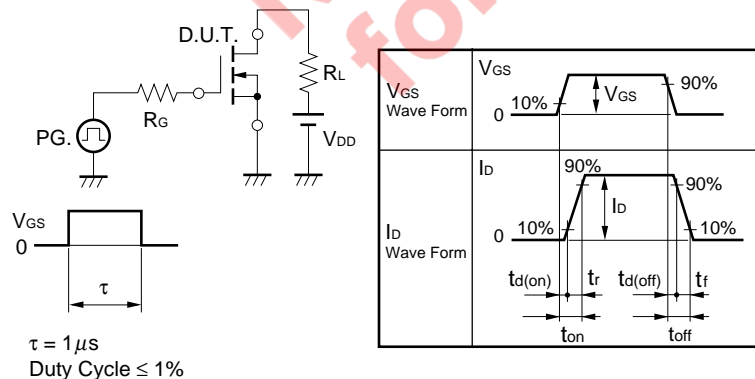
**ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C. All terminals are connected.)**

**N-channel**

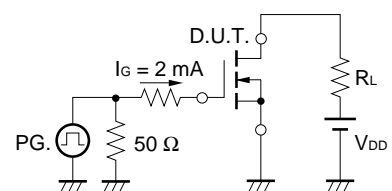
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			10	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±16 V, V <sub>DS</sub> = 0 V			±10	μA
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	1.5	2.1	2.5	V
Forward Transfer Admittance <sup>Note</sup>	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 3.4 A	3.0	7.5		S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)1</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 3.4 A		20.5	26	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 3.4 A		27	36	mΩ
	R <sub>DS(on)3</sub>	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 3.4 A		31	42	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V		760		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V		250		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		95		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 3.4 A		20		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V		140		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		50		ns
Fall Time	t <sub>f</sub>			30		ns
Total Gate Charge	Q <sub>G</sub>	I <sub>D</sub> = 6.8 A		14		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>DD</sub> = 24 V		2		nC
Gate to Drain Charge	Q <sub>GD</sub>	V <sub>GS</sub> = 10 V		5		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 6.8 A, V <sub>GS</sub> = 0 V		0.86		V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 6.8 A, V <sub>GS</sub> = 0 V		30		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100 A/μs		20		nC

**Note** Pulse: PW ≤ 350 μs, Duty Cycle ≤ 2%

**TEST CIRCUIT 1 SWITCHING TIME**



**TEST CIRCUIT 2 GATE CHARGE**

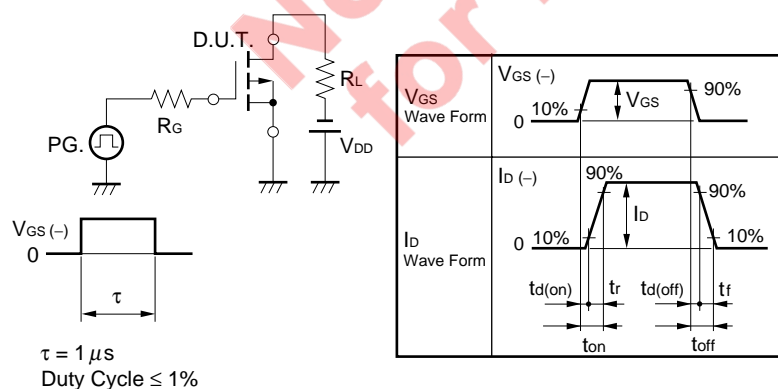


**P-channel**

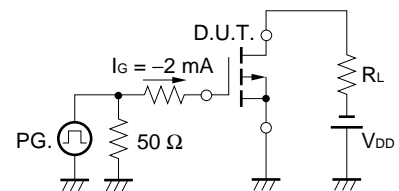
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$			-1	$\mu\text{A}$
Gate Leakage Current	$I_{GSS}$	$V_{GS} = \pm 16\text{ V}, V_{DS} = 0\text{ V}$			$\mp 10$	$\mu\text{A}$
Gate Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-1.5	-2.0	-2.5	V
Forward Transfer Admittance <b>Note</b>	$ y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -2.9\text{ A}$	3.5	8.0		S
Drain to Source On-state Resistance <b>Note</b>	$R_{DS(on)1}$	$V_{GS} = -10\text{ V}, I_D = -2.9\text{ A}$		30	36	$\text{m}\Omega$
	$R_{DS(on)2}$	$V_{GS} = -4.5\text{ V}, I_D = -2.9\text{ A}$		43	54	$\text{m}\Omega$
	$R_{DS(on)3}$	$V_{GS} = -4.0\text{ V}, I_D = -2.9\text{ A}$		49	65	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = -10\text{ V}$		900		pF
Output Capacitance	$C_{oss}$	$V_{GS} = 0\text{ V}$		300		pF
Reverse Transfer Capacitance	$C_{rss}$	$f = 1\text{ MHz}$		120		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, I_D = -2.9\text{ A}$		23		ns
Rise Time	$t_r$	$V_{GS} = -10\text{ V}$		220		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		90		ns
Fall Time	$t_f$			70		ns
Total Gate Charge	$Q_G$	$I_D = -5.8\text{ A}$		17		nC
Gate to Source Charge	$Q_{GS}$	$V_{DD} = -24\text{ V}$		2.5		nC
Gate to Drain Charge	$Q_{GD}$	$V_{GS} = -10\text{ V}$		4.0		nC
Body Diode Forward Voltage <b>Note</b>	$V_{F(S-D)}$	$I_F = 5.8\text{ A}, V_{GS} = 0\text{ V}$		0.85		V
Reverse Recovery Time	$t_{rr}$	$I_F = 5.8\text{ A}, V_{GS} = 0\text{ V}$		40		ns
Reverse Recovery Charge	$Q_{rr}$	$di/dt = 100\text{ A}/\mu\text{s}$		30		nC

**Note** Pulse:  $PW \leq 350\ \mu\text{s}$ , Duty Cycle  $\leq 2\%$

**TEST CIRCUIT 1 SWITCHING TIME**

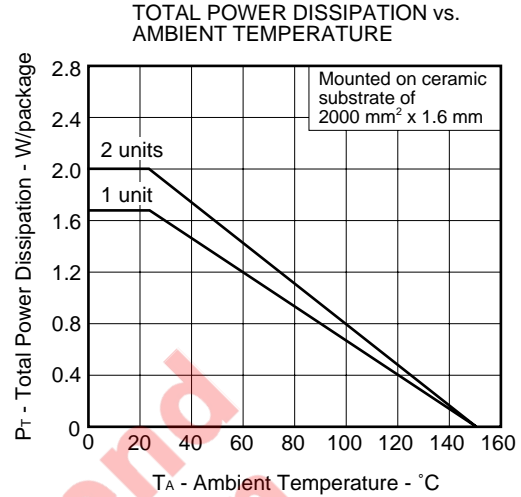
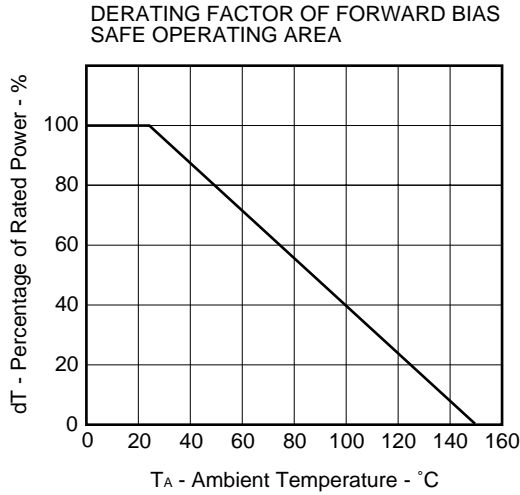


**TEST CIRCUIT 2 GATE CHARGE**

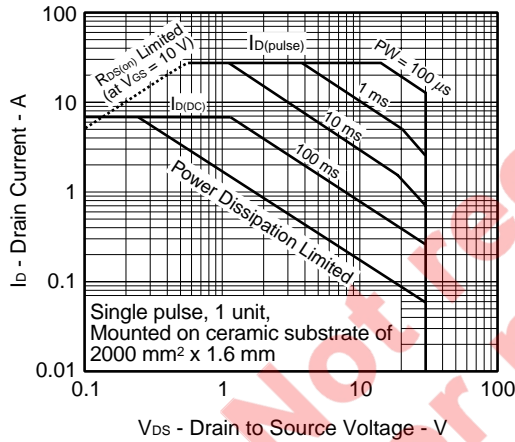


TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

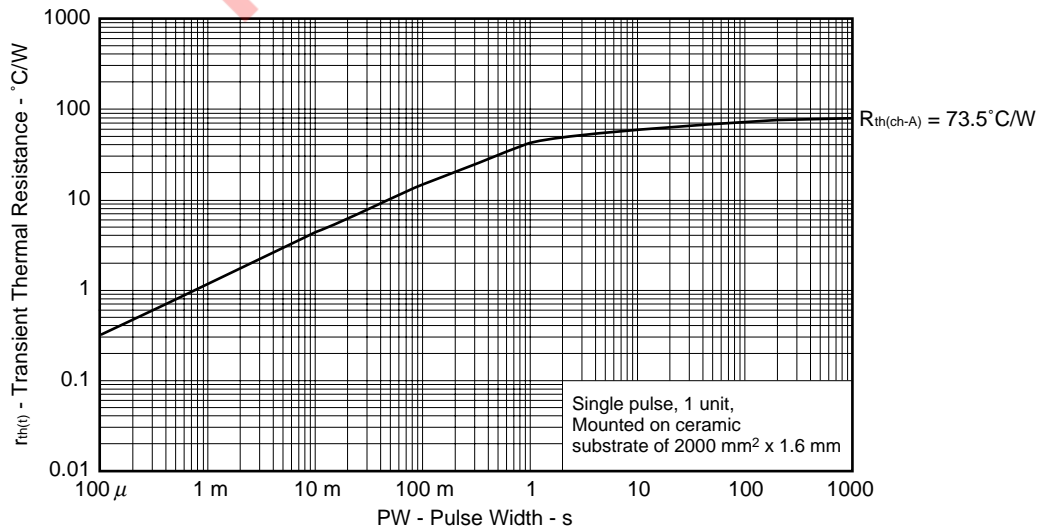
(1) N-channel



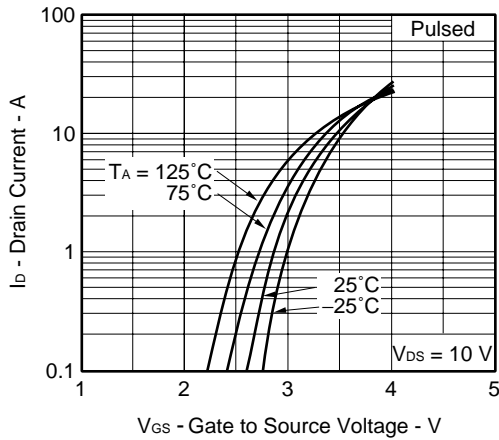
★ FORWARD BIAS SAFE OPERATING AREA



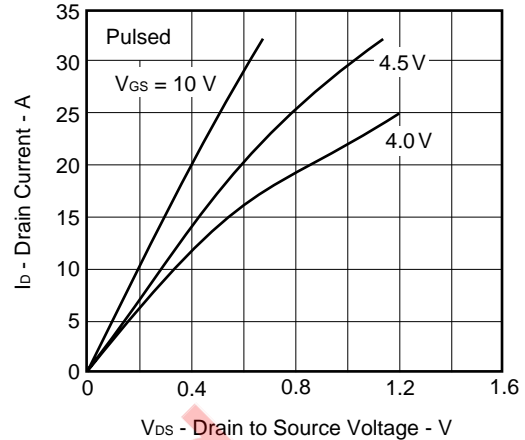
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



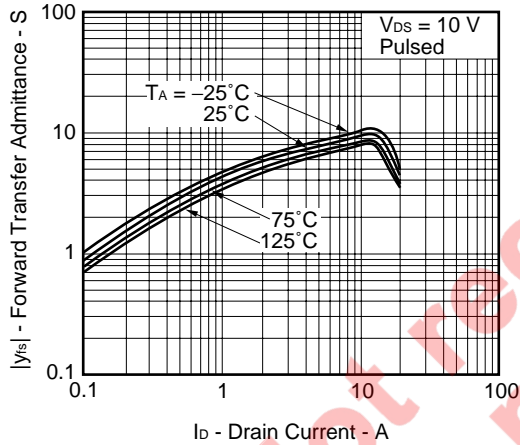
FORWARD TRANSFER CHARACTERISTICS



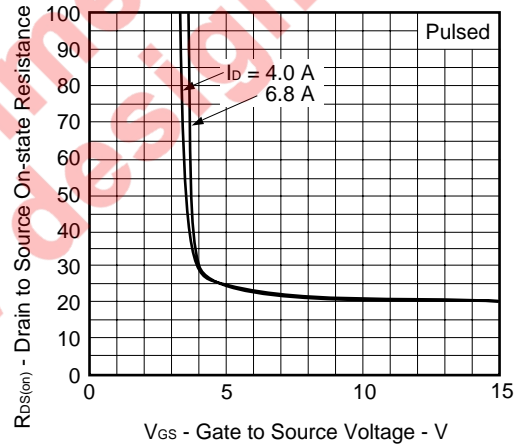
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



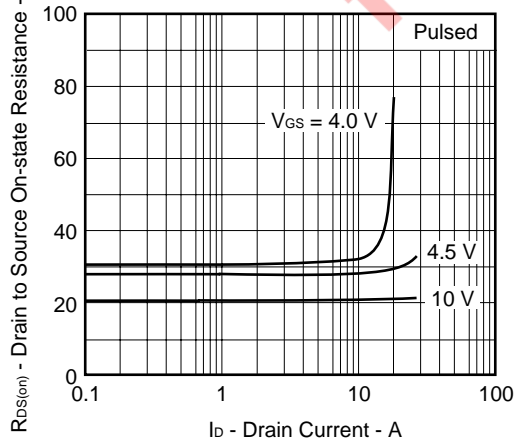
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



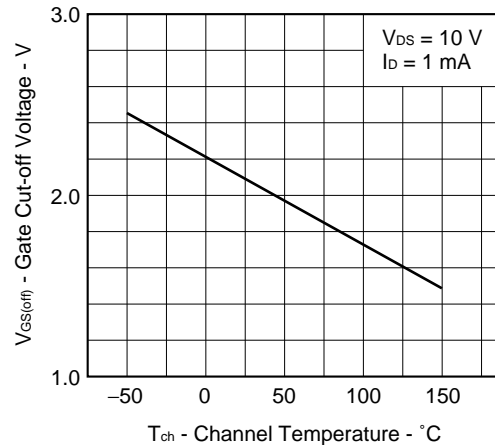
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

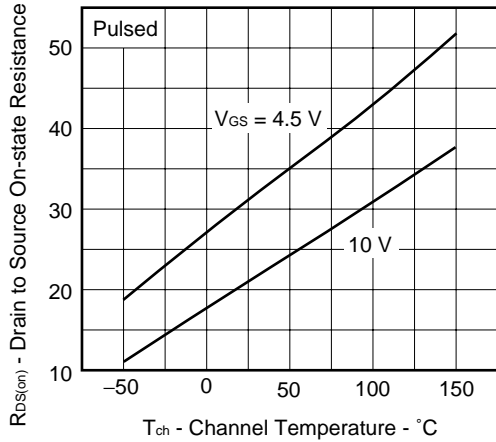


GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE

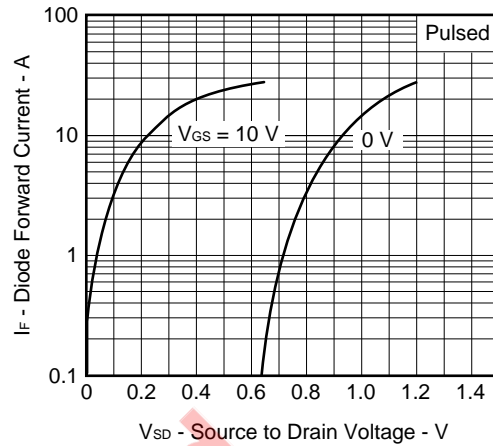




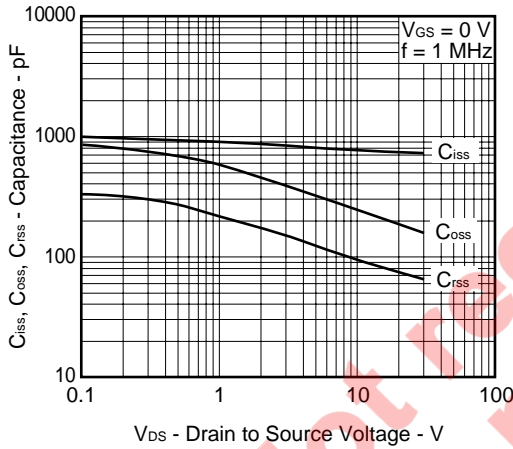
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



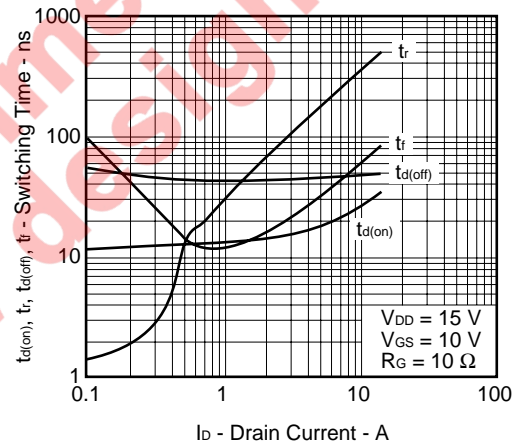
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



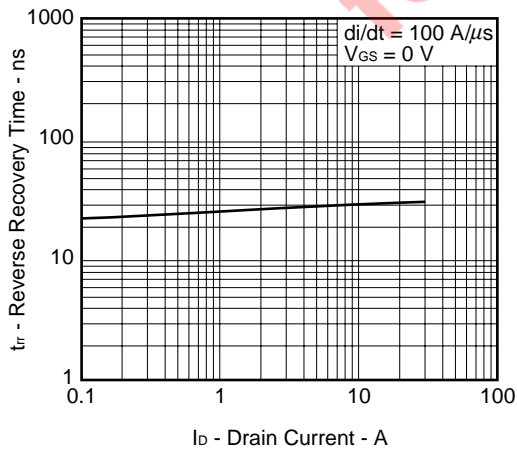
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



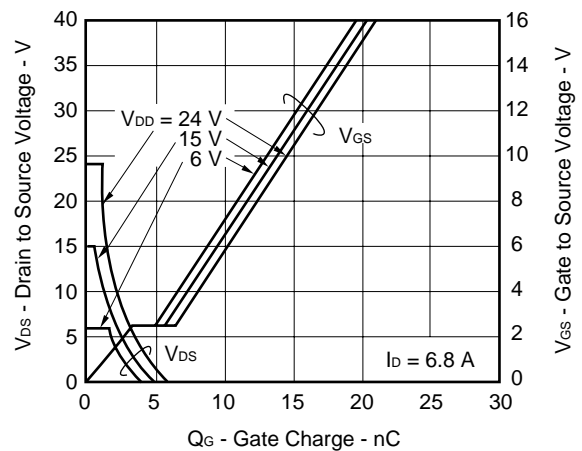
SWITCHING CHARACTERISTICS



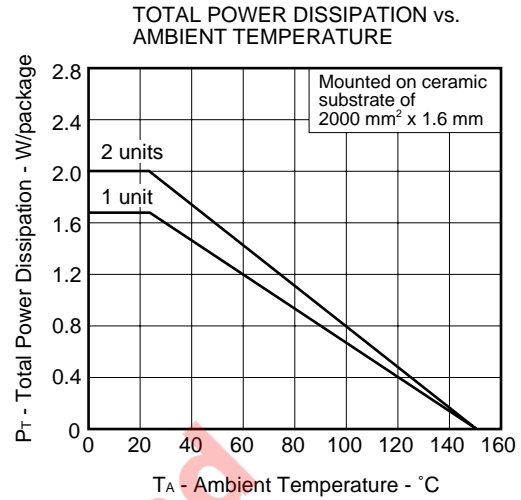
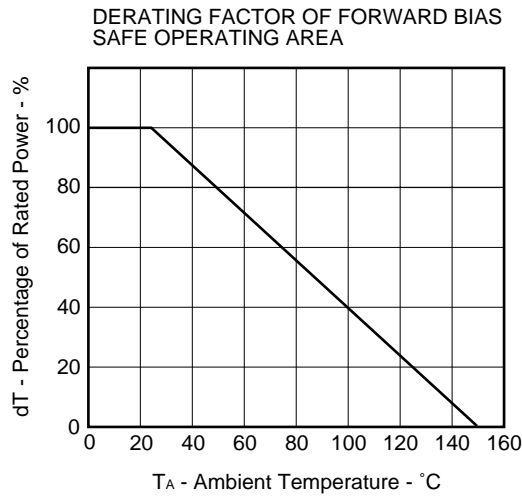
REVERSE RECOVERY TIME vs. DRAIN CURRENT



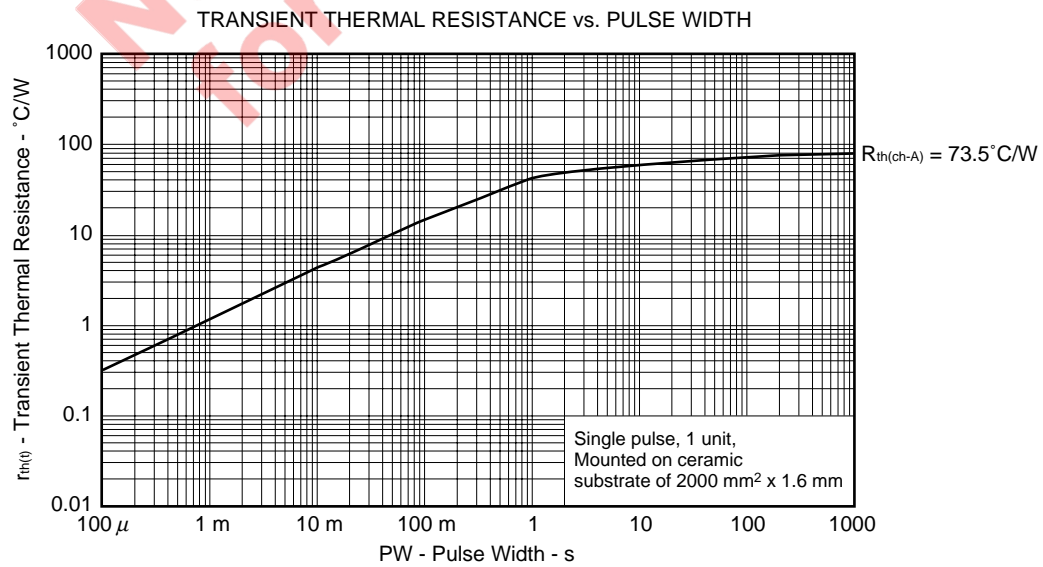
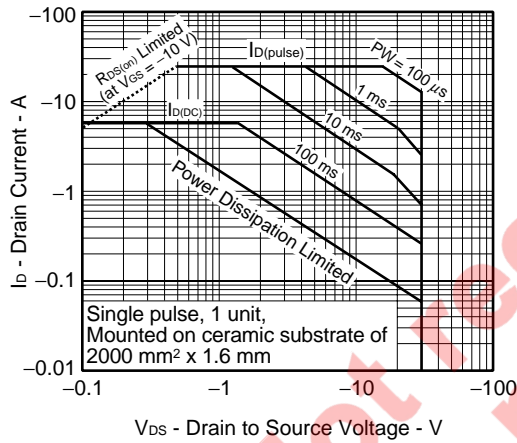
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



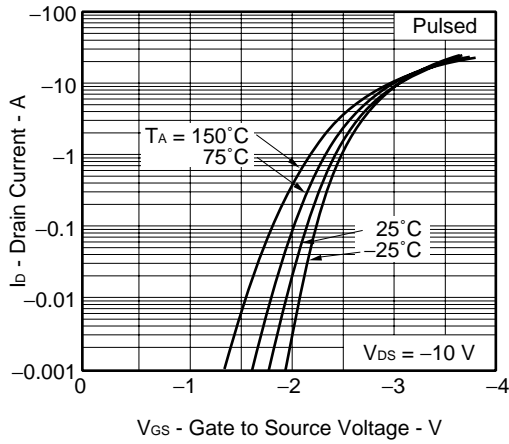
(2) P-channel



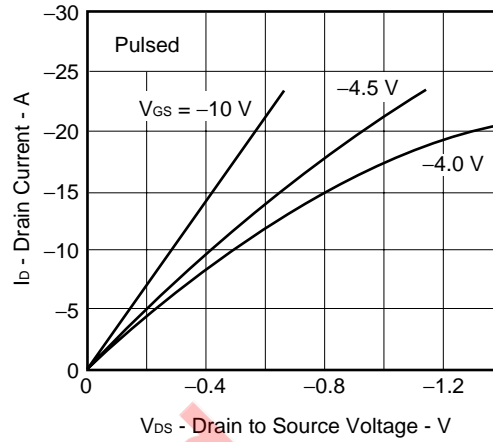
★ FORWARD BIAS SAFE OPERATING AREA



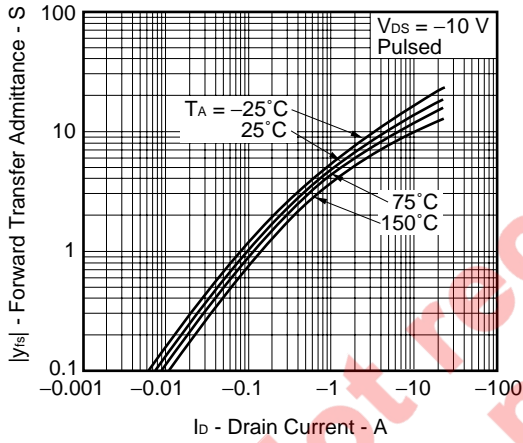
FORWARD TRANSFER CHARACTERISTICS



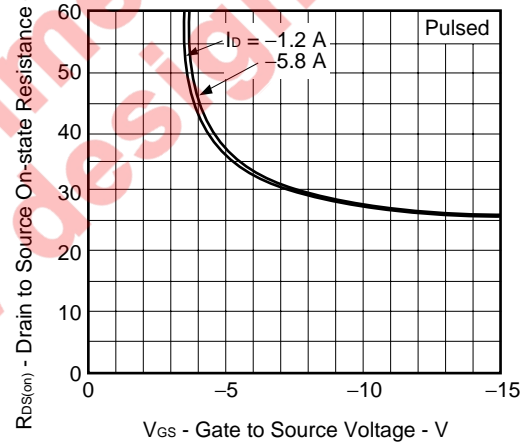
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



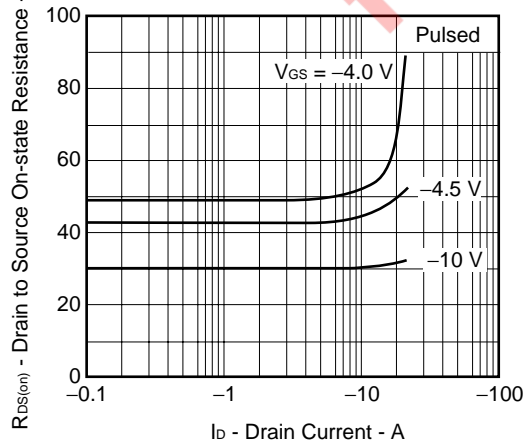
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



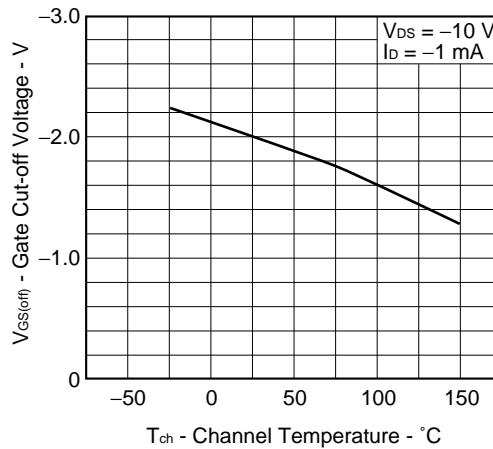
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



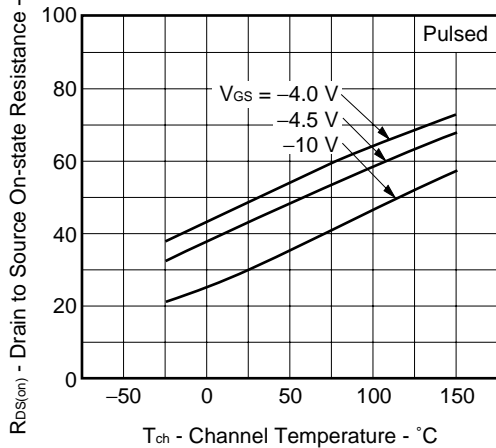
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



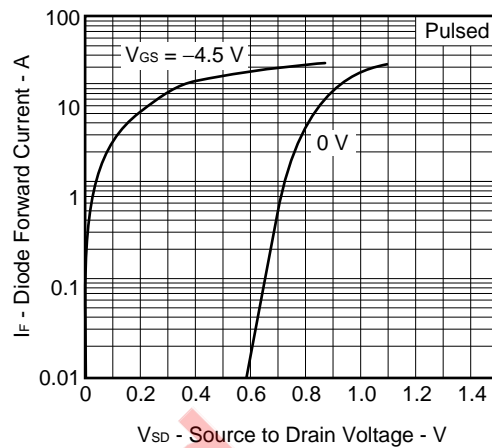
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



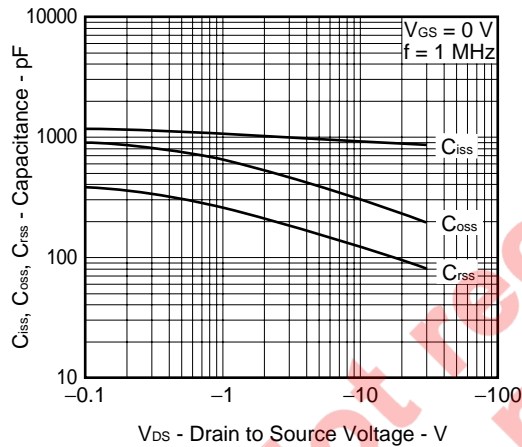
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



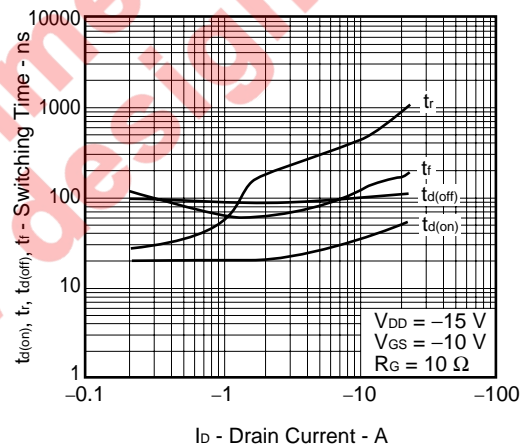
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



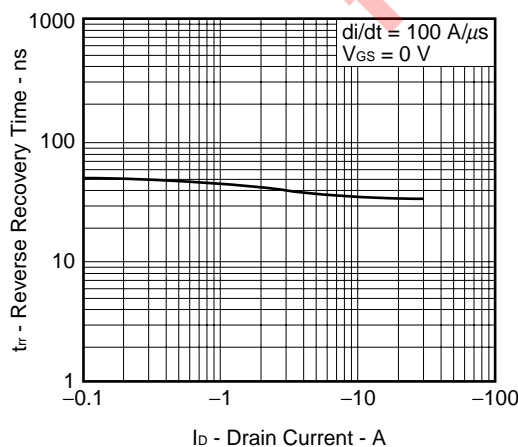
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



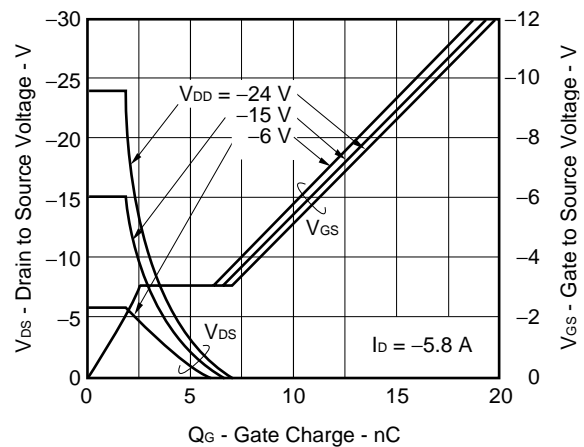
SWITCHING CHARACTERISTICS



REVERSE RECOVERY TIME vs. DRAIN CURRENT



DYNAMIC INPUT/OUTPUT CHARACTERISTICS



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